

## **AMFR Series**

# **Low-Resistance Metal Film Chip Resistor**

PROSEMI offers AEC-Q200 qualified Current Sensing Resistor





#### **Applications**

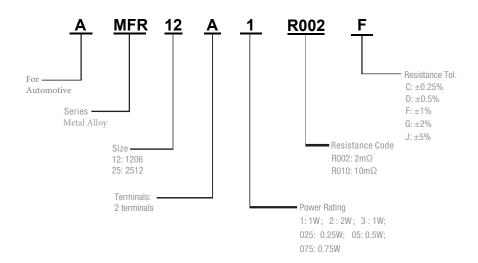
- Consumer electronics
- Computer & relative products
- Communication devices
- Measuring instrument
- Industrial / Power supply
- Battery management system



#### **Features**

- Low Resistance / TCR / Inductance (≤5NH)
- Excellent long-term stability
- High precision current sensing
- High power capability
- Halogen free and lead free
- RoHS compliant
- AEC-Q200 compliant

#### **Part Numbering System**





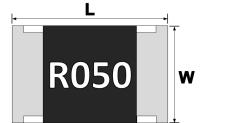
# Low-Resistance Metal Film Chip Resistor

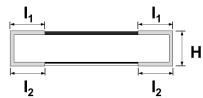
# **AMFR Series**

Type	Rating Power at 70°C	T.C.R.	Resistance l	Range(mΩ)			
туре		(ppm/°C)	C: 0.25%	D: 0.5%, F: 1.0%, G: 2.0%, J: 5.0%	Meterial	Operating Temperature(°ℂ)	
	0.25W,0.75W 0.5W, 1W	±150	-	$39m\Omega \le R < 50m\Omega$			
AMFR12		±100	-	$50m\Omega \le R < 100m\Omega$			
		±50	$470 \text{m}\Omega \leq R \leq 10\Omega$	$100m\Omega \le R \le 10\Omega$	Metal Alloy	-55~+155°C	
AMFR25	1W,2W 3W	±50	$470 \text{m}\Omega \! \leq R \! \leq \! 10\Omega$	$100m\Omega \le R \le 10\Omega$			

Туре	Rating Power at 70°C	T.C.R. (ppm/°C)	Resistance Range(mΩ) F: 1.0%, G: 2.0%, J: 5.0%	Meterial	Operating Temperature(℃)	
AMFR12	0.25W 0.5W	±200	10mΩ≦R< 39mΩ	Metal Alloy	-55~+155°C	

### Construction



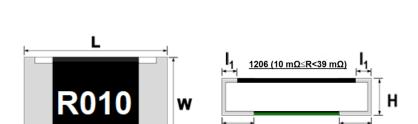


Unit: mm

Туре	L	W	Н	I <sub>1</sub>	l <sub>2</sub>	
AMFR12	3.1 ±0.1	1.6±0.1	0.55±0.1	0.4±0.2	0.45±0.2	
AMFR25	63.10.2	2 2 + 0 2	0.55±0.1	0.65±0.25	0.65±0.25	
AMFR25 3W	6.3 ±0.2	3.2±0.2	0.7±0.15	0.00±0.25	0.03±0.23	

**PROSEM** 

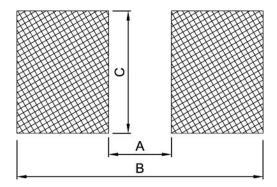




Unit: mm

Туре	L	W	Н	I <sub>1</sub>	l <sub>2</sub>
$\begin{array}{c} AMFR12 \\ (10m\Omega \! \leq \! R \! < \! 39m\Omega) \end{array}$	3.3 ±0.2	1.7±0.2	0.65±0.2	0.2±0.15	0.68±0.2

# **Recommended land pattern**



Unit: mm

Туре	Α	В	С
AMFR12	2.2	4.2	1.8
AMFR12 $(10m\Omega \le R < 39m\Omega)$	1.2	4.8	1.84
AMFR25	4.9	8.1	3.4

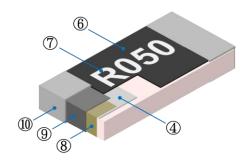


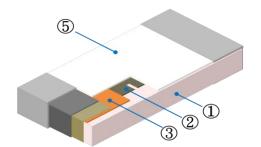
# **Product Characteristics**

Item	Test condition/ Methods	Limited
Temperature coefficient of resistance	TCR =(R-R <sub>0</sub> )/R <sub>0</sub> (T2-T1)X 10 <sup>6</sup> R <sub>0</sub> : resistance of room temperature R: resistance of 125 $^{\circ}$ C T1: Room temperature T2: Temperature at 125 $^{\circ}$ C	Refer to Spec
Short time Overload	Standard power: 6.25 times rated power whichever is less for 5 seconds.	±(1.0%+0.001Ω)
Onort time Overload	High power (2X/4X) and wide terminal type: 5 times rated power whichever is less for 5 seconds.	±(1.0 /0+0.001Ω)
Resistance to Soldering Heat	260±5℃ for 10 seconds.	±(1.0%+0.001Ω) No Visual damage
Temperature Cycling	-55℃ to +155℃, 300 cycles	±(1.0%+0.001Ω) No Visual damage
High Temperature Exposure	At 155±5℃ for 1000 hours.	±(1.0%+0.001Ω)
Bias Humidity	1,000 hours; 85°C / 85% RH, 10% of operating power. Measurement at 24±4 hours after test conclusion.	±(0.5%+0.05Ω)
Leaching	260±5℃ for 30 seconds.	>95% Coverage No Visual damage
Insulation Resistance	Apply 100VDC for 1 minute.	≥10GΩ
Damp Heat with Load	40±2°C, 90~95% R.H. RCWV or Max. working current whichever is less for 1000 hrs with 1.5 hrs "ON" and 0.5 hr "OFF"	±(1.0%+0.001Ω)
Solderability	245±5°C for 3 seconds.	>95% Coverage No Visual damage
Load Life (Endurance)	70±2°C, Rated power, or Max. working current whichever is less for 1000 hrs with 1.5 hrs "ON" and 0.5 hr "OFF".	±(0.5%+0.05Ω)
Resistance to Solvent	The tested resistor be immersed into isopropyl alcohol of 20~25°C for 60 secs. Then the resistor is left in the room for 48 hrs.	±(1.0%+0.001Ω) No Visual damage
Bending Strength	Bending once for 5 seconds D: 1206 = 3mm 2512 = 2mm	±(1.0%+0.001Ω) No Visual damage



#### Construction



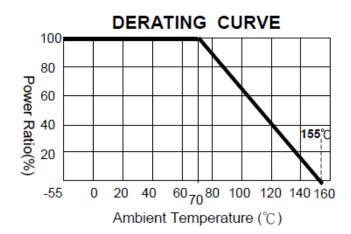


1	Alumina Substrate	6	Top Protective Overcoat
2	Resistive Layer	7	Marking
3	Bottom Inner Electrode (Cu)	8	Side Inner Electrode
4	Top Inner Electrode	9	Barrier Layer (Ni)
5	Bottom Protective Overcoat White(≧39mR) Green(<39mR)	10	Solder coating (Sn)

## **Power Derating Curve**

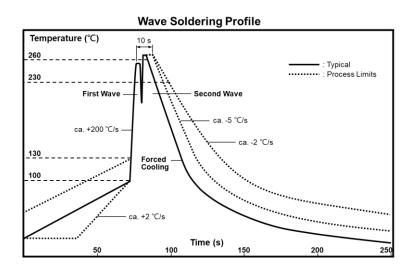
The Operating Temperature Range: -55°C ~+155°C.

Power rating or current rating is in the case based on continuous full-load at ambient temperature of 70°C. For operation at ambient temperature in excess of 70°C, the load should be derated in accordance with figure of derating Curve.

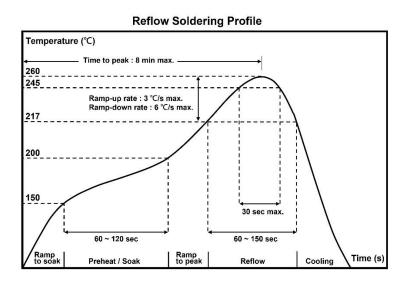




## **Wave solder Temperature condition**



## **Solder reflow Temperature condition**



- Rework temperature (hot air equipment): 350°C, 3~5seconds
- Recommended reflow methods

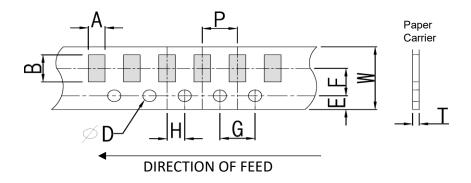
IR, vapor phase oven, hot air oven

If reflow temperatures exceed the recommended profile, devices may not meet the performance requirements.



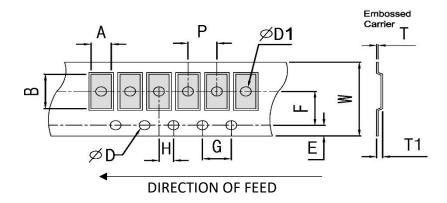
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## **Tapping & Package**



Unit: mm

Туре	<b>A</b> ±0.2	<b>B</b> ±0.2	<b>W</b> +0.2	<b>E</b> ±0.05	<b>F</b> ±0.05	<b>G</b> ±0.1	<b>H</b> ±0.05	<b>T</b> ±0.1	D	<b>P</b> ±0.1
1206	1.9	3.05	8.0	1.75	3.5	4.0	2.0	0.75	1.50+0.1	4.0



Unit: mm

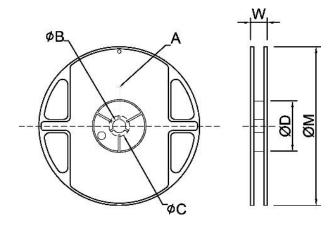
Туре	<b>A</b> ±0.2	<b>B</b> ±0.2	<b>W</b> +0.1		<b>F</b> ±0.05		<b>H</b> ±0.05	<b>T</b> ±0.1	D	<b>D1</b> ±0.1	<b>T1</b> ±0.15	<b>P</b> ±0.1
2512	3.4	6.7	12.0	1.75	5.5	4.0	2.0	0.23	1.50 +0.1	1.5	0.85	4.0



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### **Reel Specification**



Unit: mm

Туре	Quantity (pcs)	A	В	С	D	W	M
1206	5, 000	00.05	13.5±1	04 : 4	60.4	11.5±2	470+0
2512	4, 000	2.0±0.5		21±1	60±1	16.0±2	178±2

#### **Storage Data:**

Storage time at the environment temp: 25±5°C& humidity: 60±20% is valid for one year from the date of delivery.